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General Description

The MAX9324 low-skew, low-jitter, clock and data driver distributes a differential LVPECL input to four differential LVPECL outputs and one single-ended LVCMOS output. All outputs default to logic low when the differential inputs equal GND or are left open. The MAX9324 operates from 3.0V to 3.6V, making it ideal for 3.3V systems, and consumes only 25mA (max) of supply current.

The MAX9324 features low 150ps (max) part-to-part skew, low 15ps output-to-output skew, and low 1.7ps RMS jitter, making the device ideal for clock and data distribution across a backplane or board. CLK_EN and SEOUT_Z control the status of the various outputs. Asserting CLK EN low configures the differential (Q., Q_) outputs to a differential low condition and SEOUT to a single-ended logic-low state. CLK_EN operation is synchronous with the CLK_ inputs. A logic high on SEOUT_Z places SEOUT in a high-impedance state. SEOUT_Z is asynchronous with the CLK (CLK) inputs.

The MAX9324 is available in space-saving 20-pin TSSOP and ultra-small 20-pin 4mm x 4mm thin QFN packages and operates over the extended (-40°C to +85°C) temperature range.

Applications

Precision Clock Distribution Low-Jitter Data Repeater Data and Clock Driver and Buffer Central-Office Backplane Clock Distribution **DSLAM Backplane Base Station**

Features

- ♦ 15ps Differential Output-to-Output Skew
- ♦ 1.7psRMS Added Random Jitter
- ◆ 150ps (max) Part-to-Part Skew
- ♦ 450ps Propagation Delay
- ♦ Synchronous Output Enable/Disable
- **♦ Single-Ended Monitor Output**
- ♦ Outputs Assert Low when CLK, CLK are Open or
- ♦ 3.0V to 3.6V Supply Voltage Range
- ♦ -40°C to +85°C Operating Temperature Range

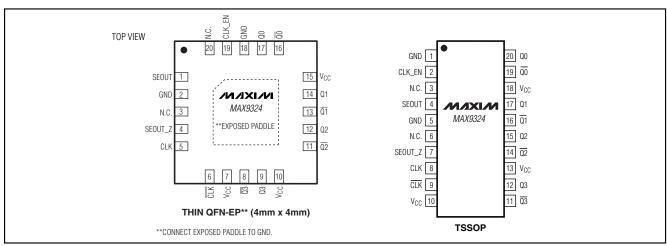
Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX9324EUP	-40°C to +85°C	20 TSSOP
MAX9324ETP*	-40°C to +85°C	20 Thin QFN-EP**

^{*}Future product—Contact factory for availability.

Functional Diagram and Typical Operating Circuit appear at end of data sheet.

Pin Configurations



MIXIM

ATE

Maxim Integrated Products 1

^{**}EP = Exposed paddle.

ABSOLUTE MAXIMUM RATINGS

V _{CC} to GND	0.3V to +4.0V
$Q_{-}, \overline{Q}_{-}, CLK, \overline{CLK}, SEOUT_{-}Z, CLK_{-}EN,$	
SEOUT to GND	0.3V to (V _{CC} + 0.3V)
CLK to CLK	±3V
SEOUT Short to GND	
Continuous Output Current (Q_, Q_)	50mA
Surge Output Current (Q_, Q_)	100mA
Continuous Power Dissipation (T _A = +70°	°C)
20-Pin TSSOP (derate 11mW/°C)	879.1mW
20-Pin 4mm × 4mm Thin QFN (derate 1	6.9mW/°C)1349.1mW

Junction-to-Ambient Thermal Resistance	in Still Air
20-Pin TSSOP	+91°C/W
20-Pin 4mm × 4mm Thin QFN	+59.3°C/W
Junction-to-Case Thermal Resistance	
20-Pin TSSOP	+20°C/W
20-Pin 4mm x 4mm Thin QFN	+2°C/W
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Soldering Temperature (10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $(V_{CC}=3.0V\ to\ 3.6V,\ differential\ outputs\ terminated\ with\ 50\Omega\ \pm1\%\ to\ (V_{CC}\ -\ 2V),\ SEOUT_Z=GND,\ CLK_EN=V_{CC},\ T_A=-40^{\circ}C\ to\ +85^{\circ}C,\ unless\ otherwise\ noted.$ Typical values are at $V_{CC}=3.3V,\ T_A=+25^{\circ}C.$) (Notes 1, 2, and 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP MAX	UNITS				
SINGLE-ENDED INPUTS (CLK_EN, SEOUT_Z)									
Input High Voltage	VIH		2	Vcc	V				
Input Low Voltage	V _{IL}		0	0.8	V				
Input Lligh Current	I	CLK_EN = VCC	-5	+5					
Input High Current	lін	SEOUT_Z = V _{CC}		150	μΑ				
Input Low Current	Lu	CLK_EN = GND	-150	-150					
Input Low Current	I _{IL}	SEOUT_Z = GND	-5	+5	μΑ				
DIFFERENTIAL INPUT (CLK, CLK	()								
Differential Input High Voltage	V _{IHD}	Figure 1	1.5	Vcc	V				
Differential Input Low Voltage	V _{ILD}	Figure 1	0	V _{CC} - 0.15	٧				
Differential Input Voltage	V _{IHD} - V _{ILD}		0.15	1.5	V				
Input Current	ICLK	V _{IHD} , V _{ILD}	-5	+150	μΑ				
DIFFERENTIAL OUTPUTS (Q_, Q	<u>-</u>								
Single-Ended Output High	VoH	Figure 1	V _{CC} - 1.4	V _{CC} - 1.0	V				
Single-Ended Output Low	V _{OL}	Figure 1	V _{CC} - 2.0	V _{CC} - 1.7	V				
Differential Output Voltage	V _{OH} - V _{OL}	Figure 1	0.6	0.85	V				
SINGLE-ENDED OUTPUT (SEOU	T)								
Output High Voltage	VoH	I _{OH} = -4mA	2.4		V				
Output Low Voltage	V _{OL}	I _{OL} = 4mA		0.4	V				
Output High-Impedance Current	loz	SEOUT_Z = V _{CC} , SEOUT = V _{CC} or GND	-10	+10	μΑ				
Output Short-Circuit Current	Ios	V _{CLK} = V _{CC} , SEOUT = GND		75	mA				
SUPPLY	•		•						
Supply Current	Icc	(Note 4)		25	mA				

AC ELECTRICAL CHARACTERISTICS

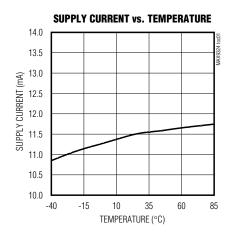
 $(V_{CC}=3.0V\ to\ 3.6V,\ differential\ outputs\ terminated\ with\ 50\Omega\ \pm1\%\ to\ (V_{CC}-2V),\ f_{CLK}\le 266MHz,\ input\ duty\ cycle=50\%,\ input\ transition\ time=125ps\ (20\%\ to\ 80\%),\ V_{IHD}=1.5V\ to\ V_{CC},\ V_{ILD}=GND\ to\ (V_{CC}-0.15V),\ V_{IHD}-V_{ILD}=0.15V\ to\ 1.5V,\ CLK_EN=V_{CC},\ SEOUT_Z=GND,\ T_A=-40°C\ to\ +85°C,\ unless\ otherwise\ noted.$ Typical values are at $V_{CC}=3.3V,\ V_{IHD}=(V_{CC}-1V),\ V_{ILD}=(V_{CC}-1.5V),\ T_A=+25°C.)$ (Note 5)

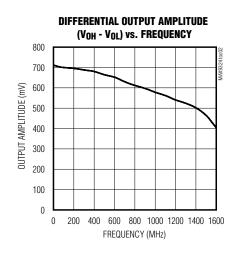
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Cwitching Fraguency	f	V _{OH} - V _{OL} ≥ 0.6V, SEOUT_Z = V _{CC}	650	800		MHz
Switching Frequency	fMAX	SEOUT_Z = GND, SEOUT	125	200		IVIHZ
Propagation Delay	t _{PHL} , t _{PLH}	CLK, CLK to Q_, Q_, Figure 1 (Note 6)	100	450	600	ps
Output-to-Output Skew	tskoo	(Note 7)			30	ps
Part-to-Part Skew	tskpp	(Note 8)			150	ps
Output Rise Time	t _R	20% to 80%, Figure 1	100	217	300	ps
Output Fall Time	tF	80% to 20%, Figure 1	100	207	300	ps
Output Duty Cycle	ODC		48	50	52	%
Added Random Jitter	t _{RJ}	f _{CLK} = 650MHz (Note 9)		1.7	3	ps(RMS)
Added Deterministic Jitter	t _D J	2e ²³ - 1 PRBS pattern, f = 650Mbps (Note 9)		83	100	PS(P-P)
Added Jitter	t _A J	V _{CC} = 3.3V with 25mV superimposed sinusoidal noise at 100kHz (Note 9)		8.5	12	ps(P-P)
Single-Ended Output Rise Time	t _R	C _L = 15pF, 20% to 80%, Figure 1		1.6	2	ns
Single-Ended Output Fall Time	tF	C _L = 15pF, 80% to 20%, Figure 1		1.6	2	ns
Single-Ended Output Duty Cycle	ODC	(Note 10)	40	52	60	%

- **Note 1:** Measurements are made with the device in thermal equilibrium.
- Note 2: Current into a pin is defined as positive. Current out of a pin is defined as negative.
- **Note 3:** DC parameters are production tested at $T_A = +25^{\circ}C$ and guaranteed by design over the full operating temperature range.
- **Note 4:** All pins open except V_{CC} and GND.
- Note 5: Guaranteed by design and characterization. Limits are set at ±6 sigma.
- Note 6: Measured from the differential input signal crosspoint to the differential output signal crosspoint.
- Note 7: Measured between the differential outputs of the same part at the differential signal crosspoint for a same-edge transition.
- **Note 8:** Measured between the differential outputs of different parts at the differential signal crosspoint under identical conditions for a same-edge transition.
- **Note 9:** Jitter added to the input signal.
- Note 10: Measured at 50% of V_{CC}.

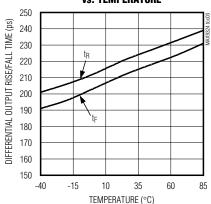
Typical Operating Characteristics

 $(V_{CC} = 3.3V, outputs terminated to (V_{CC} - 2V) through 50\Omega, SEOUT_Z = V_{CC}, CLK_EN = V_{CC}, T_A = +25^{\circ}C.)$

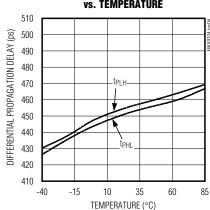








DIFFERENTIAL PROPAGATION DELAY vs. TEMPERATURE



Pin Description

PIN			FUNCTION				
TSSOP	QFN	NAME	FUNCTION				
1, 5	2, 18	GND	Ground. Provide a low-impedance connection to the ground plane.				
2	19	CLK_EN	Synchronous Output Enable. Connect CLK_EN to V_{CC} or leave floating to enable the differential outputs. Connect CLK_EN to GND to disable the differential outputs. When disabled, Q_ asserts low, \overline{Q} asserts high, and SEOUT asserts low. A 51k Ω pullup resistor to V_{CC} allows CLK_EN to be left floating.				
3, 6	3, 20	N.C.	No Connect. Not internally connected.				
4	1	SEOUT	LVCMOS/LVTTL Clock Output. SEOUT reproduces CLK when SEOUT_Z = GND. SEOUT goes high impedance when SEOUT_Z = V_{CC} . The maximum output frequency of SEOUT is 125MHz.				
7	4	SEOUT_Z	Single-Ended Clock Output Enable/Disable. Connect SEOUT_Z to GND to enable the single-ended clock output. Connect SEOUT_Z to VCC to disable the single-ended clock output. A $51k\Omega$ pulldown resistor to GND allows SEOUT_Z to be left floating.				
8	5	CLK	Noninverting Differential LVPECL Input. An internal $51k\Omega$ pulldown resistor to GND forces the outputs $(Q_{-}, \overline{Q_{-}})$ to differential low and logic low (SEOUT) when CLK and $\overline{\text{CLK}}$ are left open or at GND and the outputs are enabled.				
9	6	CLK	Inverting Differential LVPECL Input. An internal $51k\Omega$ pulldown resistor to GND forces the outputs (Q, \overline{Q}) to differential low and logic low (SEOUT) when CLK and $\overline{\text{CLK}}$ are left open or at GND and the outputs are enabled.				
10, 13, 18	7, 10, 15	Vcc	Positive Supply Voltage. Bypass V _{CC} to GND with three 0.01µF and one 0.1µF ceramic capacitors. Place the 0.01µF capacitors as close to each V _{CC} input as possible (one per V _{CC} input). Connect all V _{CC} inputs together, and bypass to GND with a 0.1µF ceramic capacitor.				
11	8	Q3	Inverting Differential LVPECL Output. Terminate $\overline{Q3}$ to (V _{CC} - 2V) with a 50 Ω ±1% resistor.				
12	9	Q3	Noninverting Differential LVPECL Output. Terminate Q3 to (V _{CC} - 2V) with a 50 Ω ±1% resistor.				
14	11	Q2	Inverting Differential LVPECL Output. Terminate $\overline{\rm Q2}$ to (V _{CC} - 2V) with a 50 Ω ±1% resistor.				
15	12	Q2	Noninverting Differential LVPECL Output. Terminate Q2 to (V _{CC} - 2V) with a 50 Ω ±1% resistor.				
16	13	Q1	Inverting Differential LVPECL Output. Terminate $\overline{\rm Q1}$ to (V _{CC} - 2V) with a 50 Ω ±1% resistor.				
17	14	Q1	Noninverting Differential LVPECL Output. Terminate Q1 to (V _{CC} - 2V) with a $50\Omega \pm 1\%$ resistor.				
19	16	$\overline{Q0}$	Inverting Differential LVPECL Output. Terminate $\overline{\text{Q0}}$ to (V _{CC} - 2V) with a 50 Ω ±1% resistor.				
20 17 Q0		Q0	Noninverting Differential LVPECL Output. Terminate Q0 to (V _{CC} - 2V) with a 50 Ω ±1% resistor.				

Detailed Description

The MAX9324 low-skew, low-jitter, clock and data driver distributes a differential LVPECL input signal to four differential LVPECL outputs and a single-ended LVC-MOS output. The differential output drivers operate at frequencies up to 800MHz. When SEOUT_Z = GND, the single-ended LVCMOS output driver operates with frequencies as high as 200MHz. The MAX9324 operates from 3.0V to 3.6V, making the device ideal for 3.3V systems.

Data Inputs

Differential LVPECL Inputs

The MAX9324 accepts a differential LVPECL input. Each differential output duplicates the differential input

signal. Terminate CLK and $\overline{\text{CLK}}$ through 50Ω to (V_{CC} - 2V) to minimize input signal reflections. Internal $51k\Omega$ pulldown resistors to GND ensure the outputs default to differential low (Q_, $\overline{\text{Q}}$) or logic low (SEOUT) when the CLK inputs are left open.

CLK_EN Input

CLK_EN enables/disables the differential outputs of the MAX9324. Connect CLK_EN to V_{CC} to enable the differential outputs. The (Q_, \overline{Q}) outputs are driven to a differential low condition when CLK_EN = GND. Each differential output pair disables following successive rising and falling edges on CLK (falling and rising edges on \overline{C} LK), after CLK_EN connects to GND. Both a rising and falling edge on CLK are required to complete the enable/disable function (Figure 2).

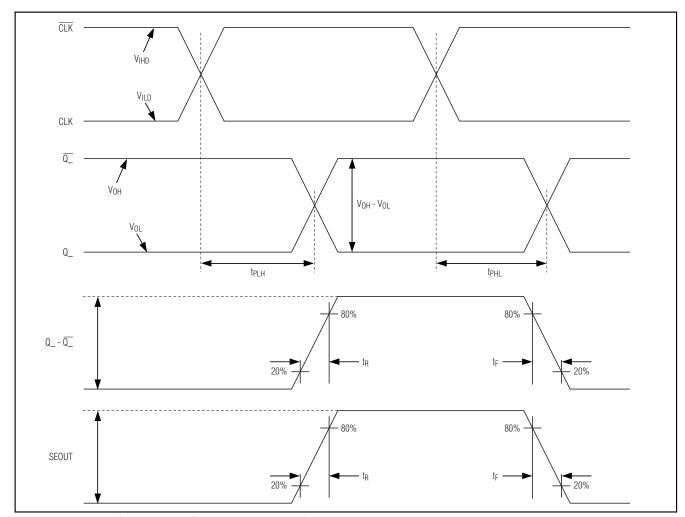


Figure 1. MAX9324 Clock Input-to-Output Delay and Rise/Fall Time

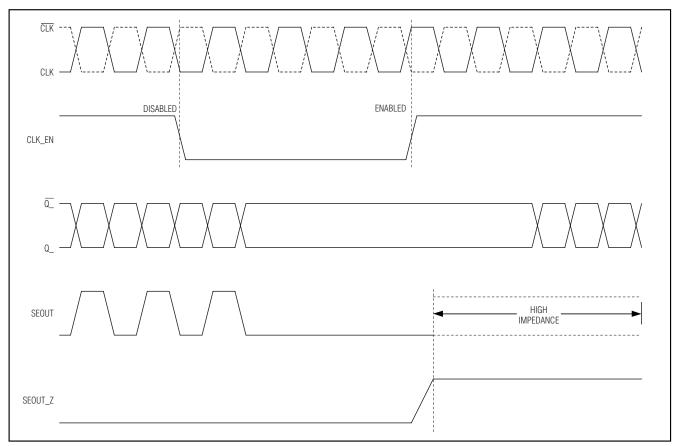


Figure 2. MAX9324 CLK_EN Timing Diagram

SEOUT_Z

SEOUT_Z enables/disables the single-ended LVCMOS output (Table 1). Connect SEOUT_Z to GND to enable the single-ended output. Connect SEOUT_Z to V_{CC} to force the single-ended output to a high-impedance state. SEOUT provides a single-ended monitor for operating frequencies as high as 200MHz.

Applications Information

Output Termination

Terminate both outputs of each differential pair through 50Ω to (V_{CC} - 2V) or use an equivalent Thevenin termination. Use identical termination on each output for the lowest output-to-output skew. Terminate both outputs when deriving a single-ended signal from a differential output. For example, using Q0 as a single-ended output requires termination for both Q0 and $\overline{\rm Q0}$.

Table 1. Control Input Table

INPUTS		OUTPUTS							
CLK_EN SEOUT_Z		Q0-Q3	<u> Q0–Q3</u>	SEOUT					
0	0	Disabled, pulled to logic low	Disabled, pulled to logic high	Enabled, logic low					
0	1	Disabled, pulled to logic low	Disabled, pulled to logic high	Disabled, high impedance					
1	0	Enabled	Enabled	Enabled					
1	1	Enabled	Enabled	Disabled, high impedance					

SEOUT provides a single-ended LVCMOS monitor output. SEOUT operates with a maximum output frequency of 200MHz.

Ensure that the output currents do not violate the current limits as specified in the *Absolute Maximum Ratings* table. Observe the device's total thermal limits under all operating conditions.

Power-Supply Bypassing

Bypass V_{CC} to GND using three 0.01µF ceramic capacitors and one 0.1µF ceramic capacitor. Place the 0.01µF capacitors (one per V_{CC} input) as close to V_{CC} as possible (see the *Typical Operating Circuit*). Use multiple bypass vias to minimize parasitic inductance.

Circuit Board Traces

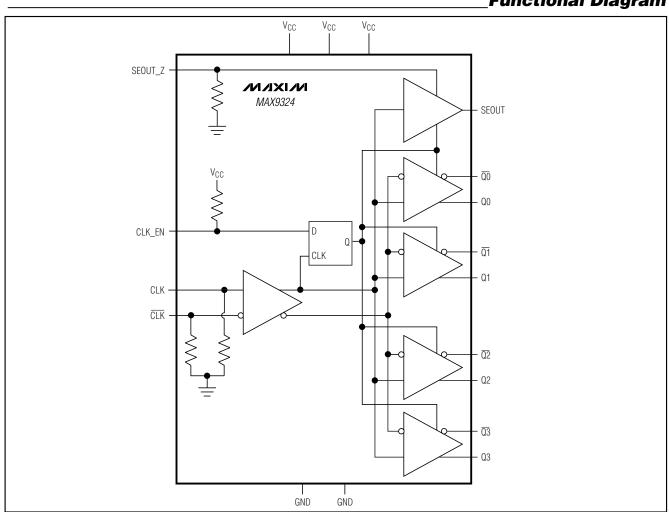
Input and output trace characteristics affect the performance of the MAX9324. Connect each input and output to a 50Ω characteristic impedance trace to minimize reflections. Avoid discontinuities in differential impedance and maximize common-mode noise immunity by maintaining the distance between differential traces and avoiding sharp corners. Minimize the number of vias to prevent impedance discontinuities. Minimize skew by matching the electrical length of the traces.

Chip Information

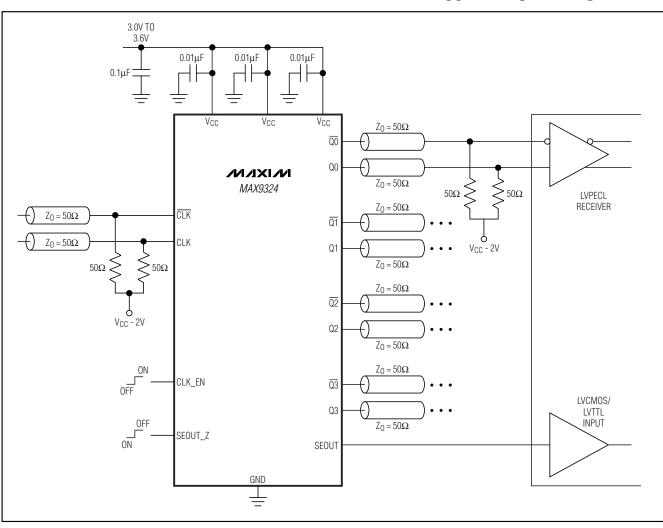
TRANSISTOR COUNT: 4430

PROCESS: BiCMOS

Functional Diagram

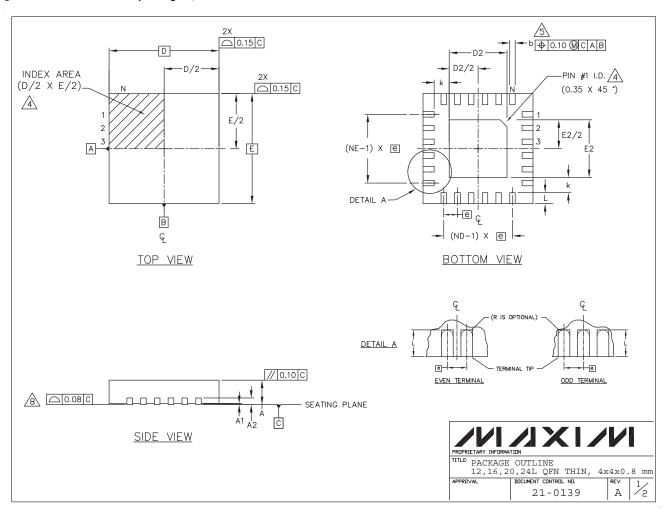


Typical Operating Circuit



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

	COMMON DIMENSIONS											
PKG	12L 4×4			16L 4×4			20L 4×4			24L 4×4		
REF.	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80
A1	0.0	0.02	0.05	0.0	0.02	0.05	0.0	0.02	0.05	0.0	0.02	0.05
A2	0.20 REF			0.20 REF			0.20 REF			0.20 REF		
b	0.25	0.30	0.35	0.25	0.30	0.35	0.20	0.25	0.30	0.18	0.23	0.30
D	3.90	4.00	4.10	3.90	4.00	4.10	3.90	4.00	4.10	3.90	4.00	4.10
Ε	3.90	4.00	4.10	3.90	4.00	4.10	3.90	4.00	4.10	3.90	4.00	4.10
е		0.80 BS0	С.	0.65 BSC.		0.50 BSC.		0.50 BSC.				
k	0.25	-	-	0.25	-	-	0.25	-	-	0.25	-	-
L	0.45	0.55	0.65	0.45	0.55	0.65	0.45	0.55	0.65	0.30	0.40	0.50
N	12			16		20		24				
ND	3		4		5		6					
NE	3			4		5		6				
Jedec Var.	WGGB				WGGC		WGGD-1 WGGD-			2		

EXPO:	SED	PAD	VAR	RIATI	DNS		
PKG.		D2		E2			
CODES	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.	
T1244-2	1.95	2.10	2.25	1.95	2.10	2.25	
T1644-2	1.95	2.10	2.25	1.95	2.10	2.25	
T2044-1	1.95	2.10	2.25	1.95	2.10	2.25	
T2444-1	2.45	2.60	2.63	2.45	2.60	2.63	

- 1. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DEGREES.
- 3. N IS THE TOTAL NUMBER OF TERMINALS.
- 4\text{\text{THE TERMINAL #1 IDENTIFIER AND TERMINAL NUMBERING CONVENTION SHALL CONFORM TO JESD 95-1 SPP-012. DETAILS OF TERMINAL #1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE ZONE INDICATED. THE TERMINAL #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEATURE.
- DIMENSION & APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25 mm AND 0.30 mm FROM TERMINAL TIP.
- 6 ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.
- 7. DEPOPULATION IS POSSIBLE IN A SYMMETRICAL FASHION.
- & COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.
- 9. DRAWING CONFORMS TO JEDEC MO220.



TITLE PACKAGE OUTLINE

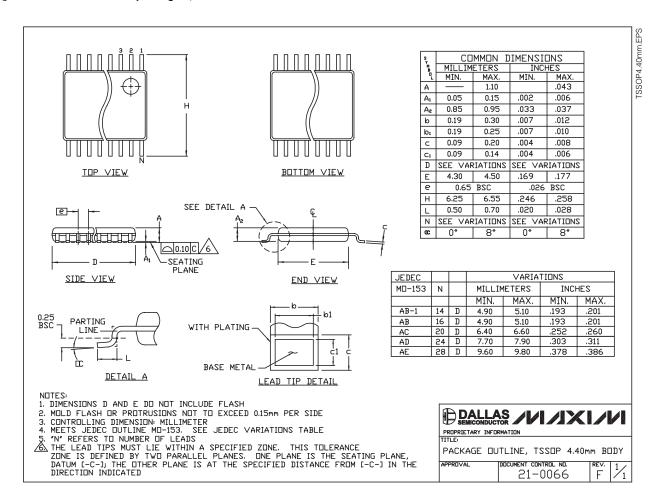
12,16,20,24L QFN THIN, 4x4x0.8 mm

VAL | DOCUMENT CONTROL NO. | REV | 2 21-0139 Α



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



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